POSITIVE VOLTAGE REGULATOR

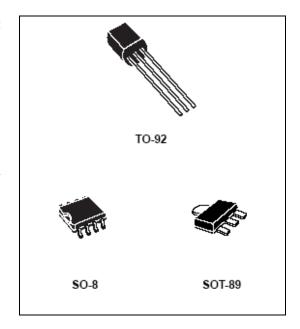
3-TERMINAL 0.1A POSITIVE VOLTAGE REGULATORS

IL78Lxx

This series of fixed-voltage monolithic integrated-circuit voltage regulators is designed for a wide range of applications. These applications include on-card regulation for elimination of noise and distribution problems associated with single-point regulation. In addition, they can be used with power-pass elements to make high current voltage regulators. Each of these regulators can deliver up to 100mA output current.

The internal limiting and thermal shutdown features of these regulators make them essentially immune to overload.

When used as a replacement for a zener diode-resistor combination, an effective improvement in output impedance can be obtained together with lower-bias current.



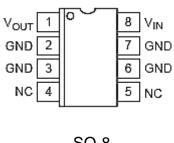
Features

- Output current Up to 100mA
- No External Components
- Internal Thermal Overload Protection
- Internal Short-Circuit Limiting
- Output Voltage of 5V, 6V, 8V, 9V, 10V, 12V, 15V, 18V and 24V

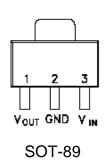
ORDERING INFORMATION

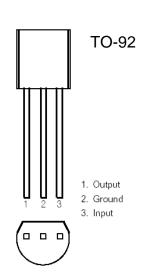
Device	Operating Temperature Range	Package	Packing
IL78LXX	T 400 / 4050 O	TO-92	Bulk
IL78LXXTA		TO-92	Taping
IL78LXXDT	$T_A = -40^{\circ} \text{ to } 125^{\circ} \text{ C}$	SO-8	Tape & Reel
IL78LXXPT		SOT-89	Tape & Reel

Pin Configuration



SO-8







Absolute Maximum Ratings

Charac	cteristic	Symbol	Value	Unit
	IL78L05 ~ IL78L10		30	
Input voltage	IL78L12 ~ IL78L18	VI	35	V
	IL78L24		40	
	TO-92		625	
Power Dissipation	SOT-89	Pd	500	mW
	SOP-8		625	
Operating junction te	mperature	Topr	-40 ~ +150	
Storage temperature		Tstg	-65 ~ +150	°C
Soldering temperatu	re and time	Tsol	260/10sec	

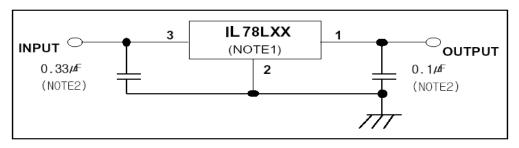
^{*} Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied.

Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

RECOMMENDED OPERATING CONDITIONS

78	Lxx	Min.	Max.	Unit
	IL78L05	7	20	
	IL78L06	8	20	
	IL78L08	10.5	23	
	IL78L09	11.5	24	
Input voltage, VI	IL78L10	12.5	25	V
	IL78L12	14.5	27	
	IL78L15	17.5	30	
	IL78L18	20.5	33	
	IL78L24	26.5	39	
Output current, lo	Output current, lo		100	mA
Operating virtual junction ten	nperature, Tj	-40	125	$^{\circ}$

TYPICAL APPLICATION



- 1. To specify an output voltage, substitute voltage for "XX"
- 2. Bypass capacitors are recommended for optimum stability and transient response and should be located as close as possible to the regulators.



IL78L05 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=10V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min	Тур.	Max.	Unit
		25℃	25°C		5	5.2	
Output voltage **	Vout	1mA≤ lo≤ 40mA 7V≤ VI≤ Vmax	-40 ~ 125℃	4.75	5	5.25	V
		1mA≤lo≤ 70mA		4.75	5	5.25	
Line regulation	Reg line	7≤ VI≤ 20V	25°C -		32	150	V
Line regulation	Neg IIIIe	8≤ VI≤ 20V			26	100	- mV
	Reg load	1mA≤ lo≤ 100mA	- 25℃		15	60	- mV
Load regulation	Reg load	1mA≤ lo≤ 40mA			8	30	
Bias current	I _B		25℃		3.8	6	mA.
Dias current	שי		125℃			5.5	IIIA
Bias current change	$ riangle$ l $_{B}$	9≤ VI≤ 20V	-40 ~ 125℃			1.5	mΛ
Dias current change	∠iβ	1 mA ≤ lo≤ 40 mA	-40 ~ 125 0			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		42		μV
Ripple rejection	RR	8≤ VI≤ 20V f=120Hz	25℃	41	49		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu\mathrm{F}$ capacitor across the input and a $0.1\mu\mathrm{F}$ capacitor across the output.



IL78L06 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=12V, Io=40mA (unless otherwise noted)

r				ı	ı	ı	
Characteistic	Symbol	Test condi	ition *	Min	Тур.	Max.	Unit
			25℃	5.75	6	6.25	
Output voltage **	Vout	1mA≤ lo≤ 40mA 8V≤ VI≤ 20V	-40 ~ 125℃	5.7	6	6.3	V
		1mA≤lo≤ 70mA		5.7	6	6.3	
Line regulation	Pog lino	8≤ VI≤ 20V	25%		35	175	V
	Reg line	9≤ VI≤ 20V	25℃		29	125	- mV
	Daniland	1mA≤ lo≤ 100mA	25℃		16	80	- mV
Load regulation	Reg load	1 mA ≤ lo≤ 40 mA			9	40	
D'accessed		25℃	25℃		3.9	6	
Bias current	I _B		125℃			5.5	- mA
Dies summet absorb	۸.I.	9≤ VI≤ 20V	40 405 %			1.5	
Bias current change	$\triangle I_B$	1 mA ≤ lo≤ 40 mA	-40 ~ 125℃			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		46		μΝ
Ripple rejection	RR	9≤ VI≤ 19V f=120Hz	25℃	40	48		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu\mathrm{F}$ capacitor across the input and a $0.1\mu\mathrm{F}$ capacitor across the output.



IL78L08 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=14V, lo=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min	Тур.	Max.	Unit
			25℃	7.7	8	8.3	
Output voltage **	Vout	1mA≤ lo≤ 40mA 10.5V≤ VI≤ 23V	-40 ~ 125℃	7.6	8	8.4	V
		1mA≤lo≤ 70mA		7.6	8	8.4	
Line regulation	Reg line	10.5≤ VI≤ 23V	25℃		42	175	m\/
	Neg iiile	11≤ VI≤ 23V	250		36	125	- mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	25℃		18	80	• mV
Load regulation	Key load	1 mA ≤ lo≤ 40 mA	250		10	40	
Dies surrent			25℃		4	6	٨
Bias current	l _B		125 ℃			5.5	mA
Diag gurrant change	$\triangle I_B$	11≤ VI≤ 23V	40 405 %			1.5	٨
Bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 125℃			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		54		μλ
Ripple rejection	RR	13≤ VI≤ 23V f=120Hz	25℃	37	46		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu\mathrm{F}$ capacitor across the input and a $0.1\mu\mathrm{F}$ capacitor across the output.



IL78L09 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, Vi=14V, lo=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min	Тур.	Max.	Unit
			25℃	806	9	9.4	
Output voltage **	Vout	1mA≤ lo≤ 40mA 12V≤ VI≤ 24V	-40 ~ 125℃	8.55	9	9.45	V
		1mA≤lo≤ 70mA		8.55	9	9.45	
Line regulation	Reg line	12≤ VI≤ 24V	25℃		45	175	m\/
	Reg line	13≤ VI≤ 24V	250		40	125	- mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	25℃		19	90	· mV
Load regulation	Reg load	1 mA ≤ lo≤ 40 mA			11	40	
Dies surrent			25℃		4.1	6	٨
Bias current	l _B		125℃			5.5	mA
Diag gurrant change	△I _B	13≤ VI≤ 24V	40 405 %			1.5	٨
Bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 125℃			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		58		μΝ
Ripple rejection	RR	13≤ VI≤ 23V f=120Hz	25℃	38	45		dB
Dropout voltage	V _D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a $0.33\mu\mathrm{F}$ capacitor across the input and a $0.1\mu\mathrm{F}$ capacitor across the output.



IL78L10 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=16V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min	Тур.	Max.	Unit
			25℃	9.6	10	10.4	
Output voltage **	Vout	1mA≤ lo≤ 40mA 13V≤ VI≤ 25V	-40 ~ 125℃	9.5	10	10.5	V
		1mA≤lo≤ 70mA		9.5	10	10.5	
Line regulation	Reg line	13≤ VI≤ 25V	25 %		51	175	-3/
	Neg iiile	14≤ VI≤ 25V	25℃ -		42	125	- mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	. 25℃		20	90	• mV
Loau regulation	ixeg load	1 mA ≤ lo≤ 40 mA	25 0		11	40	
Bias current			25℃		4.2	6	- mA
Bias current	l _B		125℃			5.5	i iiiA
Bias current change	$\triangle I_B$	14≤ VI≤ 25V	-40 ~ 125℃			1.5	Δ.
bias current change	△IB	1 mA ≤ lo≤ 40 mA	-40 ~ 125 0			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		62		μλ
Ripple rejection	RR	15≤ VI≤ 25V f=120Hz	25℃	37	44		dB
Dropout voltage	V _D		25℃		1.7		V

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.
 - Thermal effects must be taken into account separately.
 - All characteristics are measured with a 0.33μ F capacitor across the input and a 0.1μ F capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.



IL78L12 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=17V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min	Тур.	Max.	Unit
			25℃	11.5	12	12.5	
Output voltage **	Vout	1mA≤ lo≤ 40mA 14V≤ VI≤ 27V	-40 ~ 125℃	11.4	12	12.6	V
		1mA≤lo≤ 70mA		11.4	12	12.6	
Line regulation	Reg line	14.5≤ VI≤ 27V	. 25℃		55	250	7/2
	ixeg iiile	16≤ VI≤ 27V	25 C		49	200	- mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	25℃		22	100	· mV
Load regulation		1mA≤ lo≤ 40mA	20 0		13	50	
Bias current			25℃		4.3	6.5	. mA
Dias current	l _B		125℃			6	IIIA
Bias current change	△I _B	16≤ VI≤ 27V	-40 ~ 125℃			1.5	^
bias current change	∠iβ	1mA≤ lo≤ 40mA	-40 ~ 125 0			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		70		μΝ
Ripple rejection	RR	15≤ VI≤ 25V f=120Hz	25℃	37	42		dB
Dropout voltage	V _D		25℃		1.7		V

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.
 - Thermal effects must be taken into account separately.
 - All characteristics are measured with a $0.33\mu\text{F}$ capacitor across the input and a $0.1\mu\text{F}$ capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.



IL78L15 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=19V, Io=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	tion *	Min	Тур.	Max.	Unit
			25℃	14.4	15	15.6	
Output voltage **	Vout	1mA≤ lo≤ 40mA 17.5V≤ VI≤ 30V	-40 ~ 125℃	14.25	15	15.75	V
		1mA≤lo≤ 70mA		14.25	15	15.75	
Line regulation	Reg line	17.5≤ VI≤ 30V	25℃		65	300	\/
	Reg line	19≤ VI≤ 30V	25℃		58	250	- mV
	Reg load	1mA≤ lo≤ 100mA	25℃		25	150	mV
Load regulation	Key load	1 mA≤ lo≤ 40 mA			15	75	
Bias current			25℃		4.2	6.5	٨
Dias current	I _B		125℃			6	mA
Bias current change	$\triangle I_B$	19≤ VI≤ 30V	-40 ~ 125℃			1.5	٨
Bias current change	∠IB	1mA≤ lo≤ 40mA	-40 ~ 125 0			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μ
Ripple rejection	RR	18.5≤ VI≤ 28.5V f=120Hz	25℃	37	44		dB
Dropout voltage	V _D		25℃		1.7		V

- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.
 - Thermal effects must be taken into account separately.
 - All characteristics are measured with a 0.33μ F capacitor across the input and a 0.1μ F capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.



IL78L18 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=23V, lo=40mA (unless otherwise noted)

Characteistic	Symbol	Test condi	ition *	Min	Тур.	Max.	Unit
	Vout		25℃	17.3	18	18.7	
Output voltage **		1mA≤ lo≤ 40mA 20.5V≤ VI≤ 33V	-40 ~ 125℃	17.1	18	18.9	V
		1mA≤lo≤ 70mA		17.1	18	18.9	
Line regulation	Reg line	20.5≤ VI≤ 33V	25℃		70	360	\/m
Line regulation	ixeg iirie	22≤ VI≤ 33V	250		64	300	- mV
Load regulation	Reg load	1mA≤ lo≤ 100mA	. 25℃		27	180	• mV
Load regulation	iveg loau	1mA≤ lo≤ 40mA	20 0		19	90	
Bias current	I _B		25℃		4.7	6.5	٨
Dias current	ıВ		125℃			6	- mA
Bias current change	$ riangle$ l $_{B}$	22≤ VI≤ 33V	-40 ~ 125℃			1.5	
Dias current change	∠iβ	1mA≤ lo≤ 40mA	-40 ~ 125 0			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μ
Ripple rejection	RR	21.5≤ VI≤ 31.5V f=120Hz	25℃	32	36		dB
Dropout voltage	V_D		25℃		1.7		V

Notes

*. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

Thermal effects must be taken into account separately.

All characteristics are measured with a 0.33 μF capacitor across the input and a 0.1 μF capacitor across the output.



IL78L24 ELECTRICAL CHARACTERISTICS

(At specified virtual junction temperature, VI=26V, lo=40mA (unless otherwise noted)

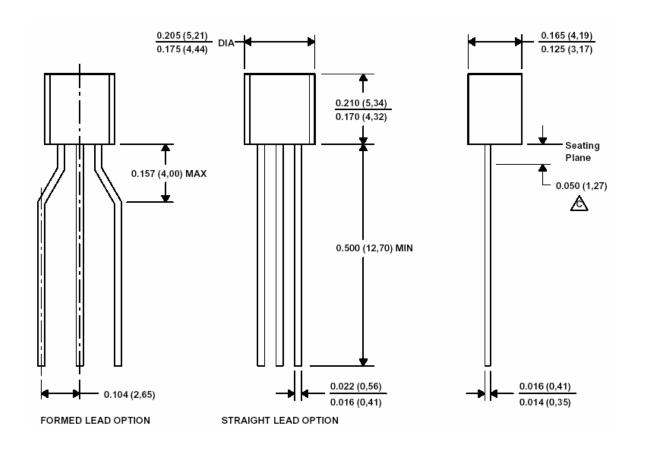
Characteistic	Symbol	Test condi	tion *	Min	Тур.	Max.	Unit
			25℃	23	24	25	
Output voltage **	Vout	1mA≤ lo≤ 40mA 26.5V≤ VI≤ 39V	-40 ~ 125℃	22.8	24	25.2	V
		1mA≤Io≤ 70mA		22.8	24	25.2	
Line regulation R	Reg line	26.5≤ VI≤ 39V	25℃		95	480	V
	Reg iiile	29≤ VI≤ 39V	250		78	400	- mV
	Reg load	1mA≤ lo≤ 100mA	25℃		41	240	mV
Load regulation	Reg load	1 mA ≤ lo≤ 40 mA	250		28	120	
Bias current			25℃		4.8	6.5	٨
Dias current	l _B		125℃			6	mA
Bias current change	$\triangle I_B$	28≤ VI≤ 39V	-40 ~ 125℃			1.5	٨
bias current change	∠IB	1mA≤ lo≤ 40mA	-40 ~ 125 C			0.1	- mA
Output noise voltage	V _N	10Hz ≤ f≤ 100kHz	25℃		82		μΝ
Ripple rejection	RR	27.5≤ VI≤ 37.5V f=120Hz	25℃	30	33		dB
Dropout voltage	V _D		25℃		1.7		V

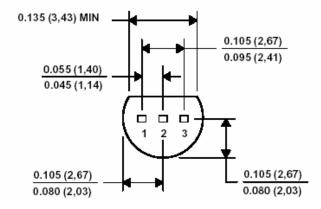
- *. Pulse testing techniques are used to maintain the junction temperature as close to the ambient temperature as possible.

 Thermal effects must be taken into account separately.
 - All characteristics are measured with a $0.33\mu F$ capacitor across the input and a $0.1\mu F$ capacitor across the output.
- **. This specification applies only for DC power dissipation permitted by absolute maximum ratings.



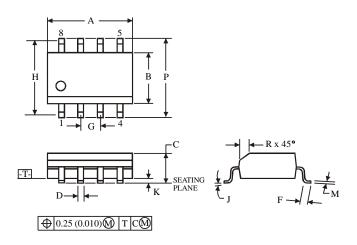
• TO-92





SO-8

D SUFFIX SOIC (MS - 012AA)



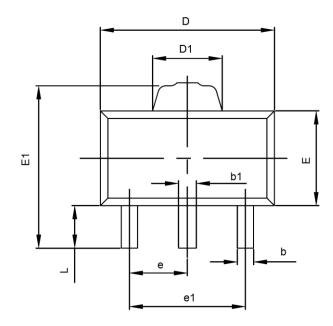
NOTES:

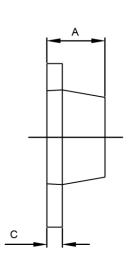
- 1. Dimensions A and B do not include mold flash or protrusion.
- 2. Maximum mold flash or protrusion 0.15 mm (0.006) per side for A; for B 0.25 mm (0.010) per side.



	Dimension, mm			
Symbol	MIN	MAX		
A	4.8	5		
В	3.8	4		
C	1.35	1.75		
D	0.33	0.51		
F	0.4	1.27		
G	1.27			
Н	5.72			
J	0°	8°		
K	0.1	0.25		
M	0.19	0.25		
P	5.8	6.2		
R	0.25	0.5		

SOT-89-3L PACKAGE OUTLINE DIMENSIONS





Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
Α	1.400	1.600	0.055	0.063
b	0.320	0.520	0.013	0.020
b1	0.360	0.560	0.014	0.022
С	0.350	0.440	0.014	0.017
D	4.400	4.600	0.173	0.181
D1	1.400	1.800	0.055	0.071
E	2.300	2.600	0.091	0.102
E1	3.940	4.250	0.155	0.167
е	1.500TYP		0.060TYP	
e1	2.900	3.100	0.114	0.122
L	0.900	1.100	0.035	0.043